Docket No.: 51876P432

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

CHANG-YOUNG JEONG, ET AL.

Art Group:

Application No.:

Examiner:

Filed:

For: ME

METHOD FOR MANUFATURING CMOS IMAGE SENSOR HAVING MICROLENS THEREIN WITH HIGH PHOTOSENSITIVITY

## INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

-1-

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

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	, 1	Blakely, Sokoloff, Taylor & Zafman LLP
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Respectfully submitted.

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-2- 51876P432

Substitute for form 1449A/PTO		Complete if Known			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)			CUDE	Application Number	
			JOUKE	Filing Date	
			ICANT	First Named Inventor	Chang-Young JEONG
				Art Unit	
				Examiner Name	
Sheet	1	of	1	Attorney Docket Number	51876P432

U.S. PATENT DOCUMENTS							
Examiner Initials*	Examiner Cite No.1 Number - Kind Code² (if known)		Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		US-6,001,540	12-14-1999	Huang et al.			
		US-2002/0102498 A1	08-01-2002	Hsin			
		US-2002/0114526 A1	08-22-2002	Dennis			
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FOREIGN PATENT DOCUMENTS							
	Cite	Foreign Patent Document			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T6	
	No.¹	Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document		T°	
		JP 04-025073	01-28-1992	TOPPAN PRINTING CO LTD		Ab	stra
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		JP 2001-094085	04-06-2001	NEC CORP			stra
		JP 04-129268\	04-03-1992	TOSHIBA CORP		Ab	stra

Examiner	Date	
Signature	Considered	

<sup>\*</sup>Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

<sup>&</sup>lt;sup>1</sup>Applicant's unique citation designation number (optional). <sup>2</sup>See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.

## **Information Disclosure Statement**

New U.S. Patent Application for METHOD FOR MANUFACTURING CMOS IMAGE SENSOR HAVING MICROLENS THEREIN WITH HIGH PHOTOSENSITIVITY Our Ref. No.: P03H8003/US/gy

## Reference No.:

- (1) US Patent No. 6,001,540
- (2) US Publication No. 2002/0102498 A1
- (3) US Publication No. 2002/0114526 A1
- (4) JP Laid-Open No. 4-25073
- (5) JP Laid-Open No. 6-326285
- (6) JP Laid-Open No. 6-326287
- (7) JP Laid-Open No. 8-1809
- (8) JP Laid-Open No. 5-29590
- (9) JP Laid-Open No. 2001-94085
- (10) JP Laid-Open No. 4-129268